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 Susan J. Shultz

Box AF  
 Expedited Procedure  
 Examining Group 2829  
 PATENT 740756-2101

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re PATENT application of:	)	Art Unit:	2829
Shunpei YAMAZAKI et al.	)	Examiner:	Evan T. PERT
Application No.: 09/502,675	)		
Filed: February 11, 2000	)		
For: SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THEREFOR	)		

**AMENDMENT AFTER FINAL**

Commissioner for Patents  
 Washington, D.C. 20231

Dear Sir:

In response to the Examiner's Final Office Action mailed April 1, 2002, the period for responding having been extended two (2) months, please consider the following amendments and remarks in connection with the above-identified application.

**IN THE CLAIMS:**

Please cancel claim 2 without prejudice or disclaimer to the subject matter disclosed therein.

Please amend claims 1, 9, 18 and 27 as follows.

1. (Twice Amended) A semiconductor device comprising a driver circuit and a pixel section over a substrate, wherein:
  - a) said driver circuit includes:
    - a first thin film transistor comprising:
      - a channel forming region and a third impurity region having n-type conductivity, wherein the channel forming region and the third impurity region are overlapped with a gate electrode;
      - and